

Technical Data Data Sheet N0445, Rev. -

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.40 grams (approx.)
- Mounting Position: Any
- Marking: Type Number

Marking Diagram:



Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

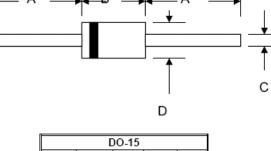
Device	Package	Shipping
FR201-FR207	DO-15 (Pb-Free)	3000pcs / tape

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

• Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 II (86) 25-87123907 • • FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •

FR201-FR207 2.0A FAST RECOVERY RECTIFIER

Green Products



DO-15						
Dim	Min	Max	Min	Max		
Α	25.4	—	1.000	—		
В	5.50	7.62	0.217	0.300		
С	0.71	0.864	0.028	0.034		
D	2.60	3.60	0.102	0.142		
	In mm		In inch			

Where XXXXX is YYWWL

FR207	= Part Name				
SSG	= SSG				
YY	= Year				
WW	= Week				
L	= Lot Number				



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Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	FR201	FR202	FR203	FR204	FR205	FR206	FR207	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm Vrwm Vr	50	100	200	400	600	800	1000	v
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	v
Average Rectified Output Current (Note 1) @T _A = 55°C	lo	2.0					А		
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	60					А		
Forward Voltage @I _F = 2.0A	Vfm	1.2					V		
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	IRM	5.0 100					μA		
Reverse Recovery Time (Note 2)	trr	150 250 500		00	nS				
Typical Junction Capacitance (Note 3)	Cj	30					pF		
Operating Temperature Range	Tj	-65 to +125				°C			
Storage Temperature Range	Тѕтс	-65 to +150				°C			

*Glass passivated forms are available upon request

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

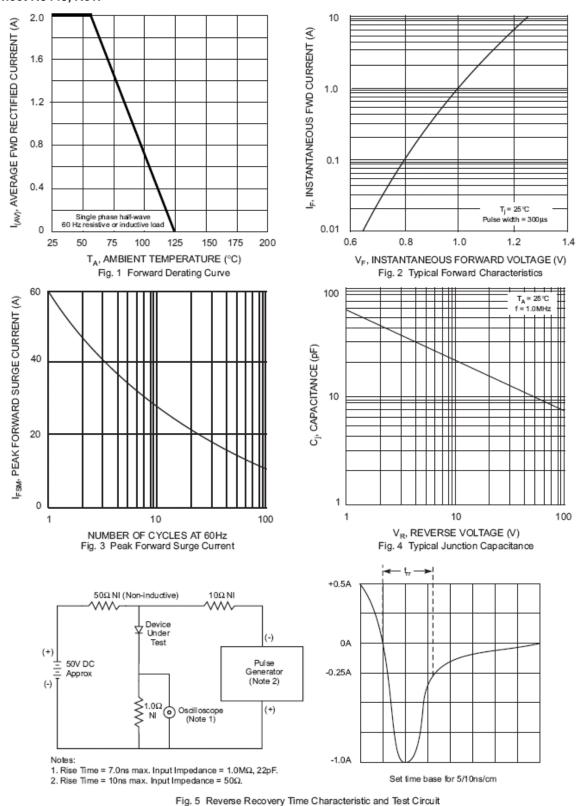
- 2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.
- 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



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